

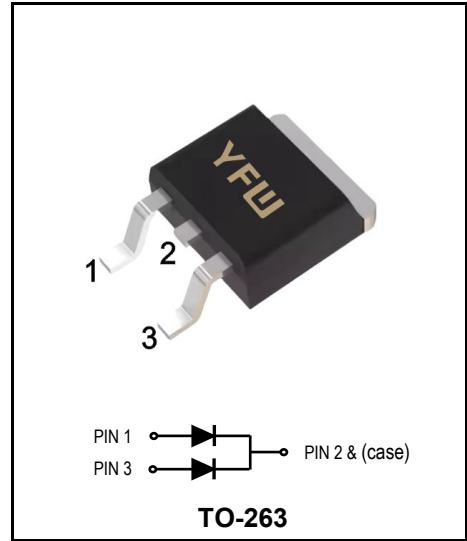
Super Fast Rectifiers
Reverse Voltage - 600V
Forward Current - 10A

FEATURES

- ◆ Glass passivated chip junctions
- ◆ Super fast recovery time for switching mode application
- ◆ High Forward Surge Capability
- ◆ Low Reverse Current
- ◆ Lead free in compliance with EU RoHS 2011/65/EU directive

MECHANICAL DATA

- ◆ Circuit figure: Common Cathode
- ◆ Leads: Solderable per mil-std-202, Method 208
- ◆ Polarity: as marked
- ◆ Mounting torque: 5 in-lbs maximum
- ◆ Terminals: Puretin plated



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (TA=25°C)

RATINGS	SYMBOL	Value	Units
Maximum repetitive reverse voltage	V_{RRM}	600	V
Maximum RMS voltage	V_{RMS}	420	V
Maximum DC blocking voltage	V_{DC}	600	V
Maximum average forward current	I_{AV}	10	A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	150	A
Typical thermal resistance per diode (Note 1)	R_{θ-JC}	2.5	°C/W
Operation Junction Temperature and Storage Temperature	T_J, T_{STG}	-55 ~ +150	°C
CHARACTERISTICS			
Typical forward voltage per leg at 5A	V_F	1.7	V
Maximum average reverse current at rated DC blocking voltage	I_R	5 250	μA
Typical reverse recovery time (Note 2)	T_{RR}	35	nS

Notes: 1. Thermal resistance from junction to case.
2. Test conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A.

Ratings And Characteristic Curves

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

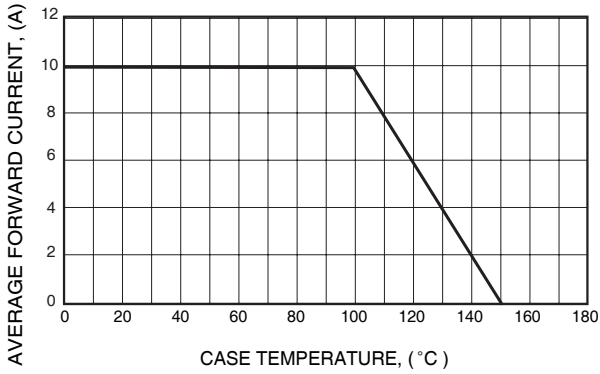


FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

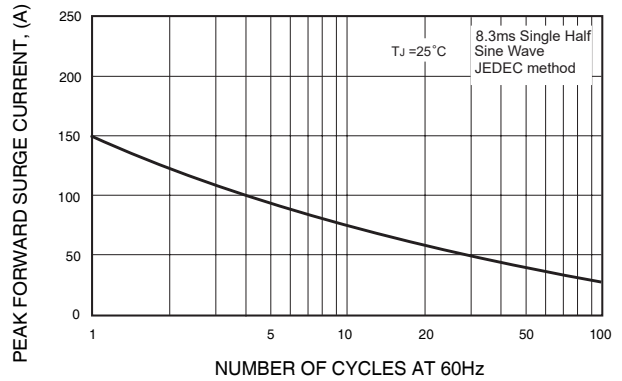


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

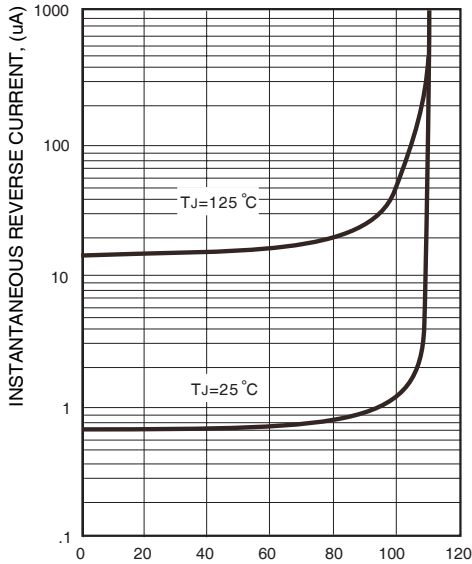


FIG. 2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

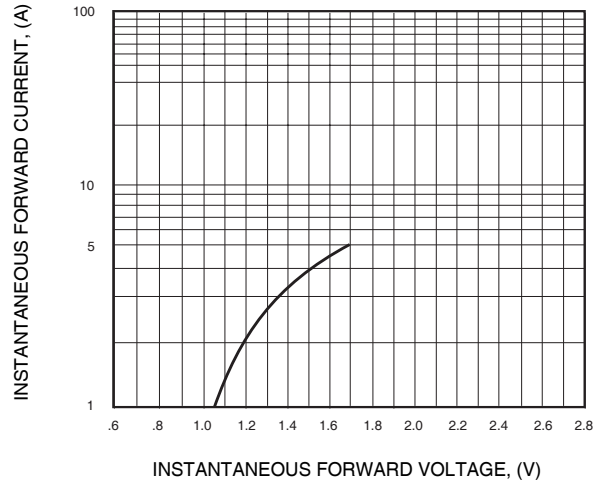
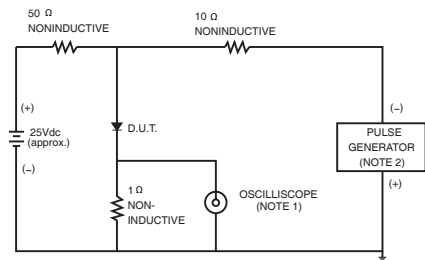
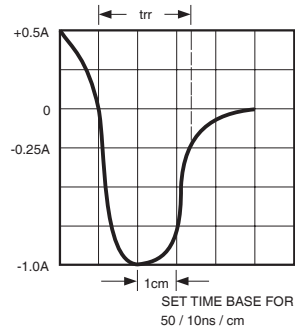


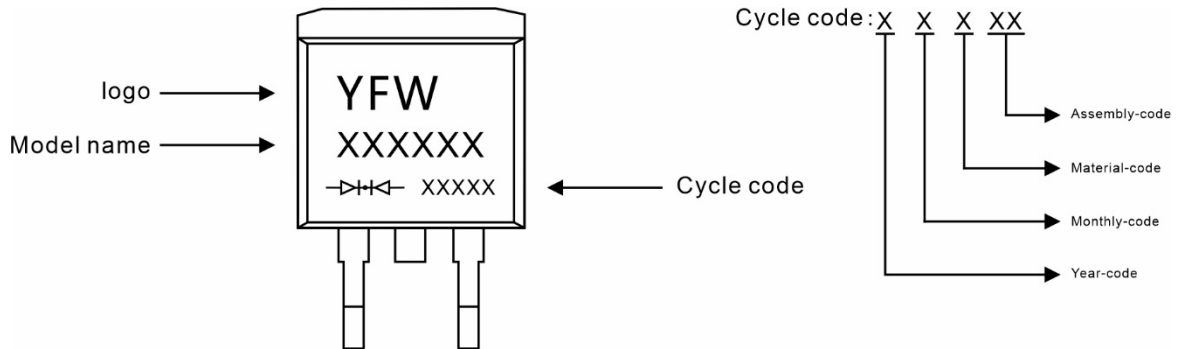
FIG.6- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.



Marking Diagram



Ordering information

Model name	Package	Unit Weight	Base Quantity	Packing Quantity
MUR1060D	TO-263	0.04oz(1.16g)	800pcs/reel	1600pcs/box 8000pcs/Carton

Package Dimensions

TO-263

Dim	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.30	4.70	0.169	0.185
A1	0.00	0.15	0.000	0.006
A2	4.30	4.55	0.169	0.179
B	1.10	1.50	0.043	0.059
b	0.70	0.90	0.028	0.035
b1	1.20	1.50	0.047	0.059
c	0.30	0.60	0.012	0.024
c1	1.17	1.37	0.046	0.054
D	9.90	10.20	0.390	0.402
E	8.50	8.90	0.335	0.350
e	2.44	2.64	0.096	0.104
e1	4.88	5.28	0.192	0.208
L	15.00	15.30	0.591	0.602
L1	5.20	5.40	0.205	0.213
L2	2.40	2.60	0.094	0.102
L3	1.60	1.80	0.063	0.071

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